DATA SHEET

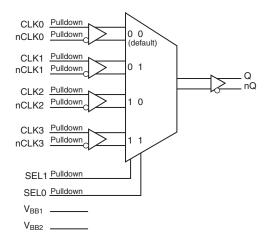
General Description

The ICS853S057I is a 4:1 Differential-to-3.3V or 2.5V LVPECL/ECL Clock/Data Multiplexer which can operate up to 3GHz. The ICS853S057I has 4 differential selectable clock input pairs. The CLK, nCLK input pairs can accept LVPECL, LVDS, CML or SSTL levels. The fully differential architecture and low propagation delay make it ideal for use in clock distribution circuits. The multiplexer select control inputs have ECL/LVPECL interface levels. The select pins have internal pulldown resistors.

Features

- · High speed 4:1 differential muliplexer
- One differential 3.3V, 2.5V LVPECL/ECL output
- Four differential CLKx, nCLKx input pairs
- Differential CLKx, nCLKx pairs can accept the following interface levels: LVPECL, LVDS, CML, SSTL
- Maximum input/output frequency: 3GHz
- Additive phase jitter, RMS @ 622.08MHz: 0.073ps (typical)
- Part-to-part skew: 250ps (maximum)
- Propagation delay: 615ps (maximum)
- LVPECL mode operating voltage supply range: $V_{CC} = 2.375V$ to 3.465V, $V_{EE} = 0V$
- ECL mode operating voltage supply range: $V_{CC} = 0V$, $V_{EE} = -3.465V$ to -2.375V
- -40°C to 85°C ambient operating temperature
- Available in lead-free (RoHS 6) packages

Block Diagram



Pin Assignment

| Vcc□ | 1 | 20 | □Vcc |
|-------------------|----|----|--------------------|
| CLK0□ | 2 | 19 | □ SEL1 |
| nCLK0□ | 3 | 18 | □SEL0 |
| CLK1 ☐ | 4 | 17 | □Vcc |
| nCLK1□ | 5 | 16 | □Q |
| CLK2□ | 6 | 15 | □nQ |
| nCLK2□ | 7 | 14 | □Vcc |
| CLK3□ | 8 | 13 | ☐ V _{BB1} |
| nCLK3□ | 9 | 12 | ☐ V _{BB2} |
| V _{EE} □ | 10 | 11 | ☐ VEE |

ICS853S057I

20-Lead TSSOP 6.5mm x 4.4mm x 0.925mm package body G Package Top View

Table 1. Pin Descriptions

| Number | Name | 1 | Гуре | Description |
|---------------|--------------------|--------|----------|---|
| 1, 14, 17, 20 | V _{CC} | Power | | Positive supply pins. |
| 2 | CLK0 | Input | Pulldown | Non-inverting differential clock input. |
| 3 | nCLK0 | Input | Pulldown | Inverting differential clock input. |
| 4 | CLK1 | Input | Pulldown | Non-inverting differential clock input. |
| 5 | nCLK1 | Input | Pulldown | Inverting differential clock input. |
| 6 | CLK2 | Input | Pulldown | Non-inverting differential clock input. |
| 7 | nCLK2 | Input | Pulldown | Inverting differential clock input. |
| 8 | CLK3 | Input | Pulldown | Non-inverting differential clock input. |
| 9 | nCLK3 | Input | Pulldown | Inverting differential clock input. |
| 10, 11 | V _{EE} | Power | | Negative supply pins. |
| 12, 13 | V_{BB2}, V_{BB1} | Output | | ECL reference outputs. |
| 15, 16 | nQ, Q | Output | | Differential output pair. ECL/LVPECL interface levels. |
| 18, 19 | SEL0, SEL1 | Input | Pulldown | Clock select inputs. ECL/LVPECL or LVCMOS interface levels. |

NOTE: *Pulldown* refers to internal input resistors. See Table 2, *Pin Characteristics*, for typical values.

Table 2. Pin Characteristics

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-----------------------|-------------------------|-----------------|---------|---------|---------|-------|
| C _{IN} | Input Capacitance | | | 4 | | pF |
| R _{PULLDOWN} | Input Pulldown Resistor | | | 51 | | kΩ |

Function Tables

Table 3. Control Input Function Table

| Contro | Clock Out | |
|--------|-------------|-------------|
| SEL1 | SEL0 | Q, nQ |
| 0 | 0 (default) | CLK0, nCLK0 |
| 0 | 1 | CLK1, nCLK1 |
| 1 | 0 | CLK2, nCLK2 |
| 1 | 1 | CLK3, nCLK3 |

Absolute Maximum Ratings

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

| Item | Rating |
|--|---------------------------------|
| Supply Voltage, V _{CC} | 4.6V |
| Inputs, V _I | -0.5V to V _{CC} + 0.5V |
| Outputs, I _O | |
| Continuous Current | 50mA |
| Surge Current | 100mA |
| Package Thermal Impedance, θ_{JA} | 87.2°C/W (0 mps) |
| Storage Temperature, T _{STG} | -65°C to 150°C |

DC Electrical Characteristics

Table 4A. Power Supply DC Characteristics, $V_{CC} = 2.375V$ to 3.465V; $V_{EE} = 0V$, $T_A = -40^{\circ}C$ to $85^{\circ}C$

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-----------------|-------------------------|-----------------|---------|---------|---------|-------|
| V _{CC} | Positive Supply Voltage | | 2.375 | 3.3 | 3.465 | V |
| I _{EE} | Power Supply Current | | | | 25 | mA |

Table 4B. DC Characteristics, $V_{CC} = 2.375V$ to 3.465V; $V_{EE} = 0V$, $T_A = -40^{\circ}C$ to $85^{\circ}C$

| Symbol | Parameter | | Test Conditions | Minimum | Typical | Maximum | Units |
|------------------|------------------------|------------------------|--|---------|---------|------------------------|-------|
| V_{PP} | Input Peak-to-Peak Vol | tage; NOTE 1 | | 0.15 | | 1.3 | V |
| V _{CMR} | Common Mode Range; | NOTE 1, 2 | | 0.5 | | V _{CC} - 0.85 | V |
| I _{IH} | Input High Current | CLK[0:3], nCLK[0:3] | V _{CC} = V _{IN} = 3.465V or 2.625V | | | 150 | μΑ |
| I _{IL} | Input Low Current | CLK[0:3], nCLK[0:3] | $V_{CC} = 3.465V \text{ or } 2.625V,$ $V_{IN} = 0V$ | -10 | | | μA |

NOTE 1: V_{IL} should not be less than -0.3V.

NOTE 2: Common mode voltage is defined as VIH.

Table 4C. LVPECL DC Characteristics, V_{CC} = 2.375V to 3.465V; V_{EE} = 0V, T_A = -40°C to 85°C

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|--------------------|-----------------------------------|-----------------|-----------------------|---------|-----------------------|-------|
| V _{OH} | Output High Voltage; NOTE 1 | | V _{CC} – 1.4 | | V _{CC} - 0.9 | V |
| V_{OL} | Output Low Voltage; NOTE 1 | | $V_{CC} - 2.0$ | | V _{CC} – 1.7 | V |
| V _{swing} | Peak-to-Peak Output Voltage Swing | | 0.6 | | 1.0 | V |

NOTE 1: Outputs terminated with 50Ω to V_{CC} – 2V.

Table 4D. ECL DC Characteristics, $V_{CC} = 0V$; $V_{EE} = 2.375V$ to 3.465V, $T_A = -40^{\circ}C$ to $85^{\circ}C$

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|--------------------|----------------------------------|-----------------|---------|---------|---------|-------|
| V _{OH} | Output High Voltage; NOTE 1 | | -1.125 | | -0.935 | V |
| V _{OL} | Output Low Voltage; NOTE 1 | | -1.895 | | -1.67 | V |
| V_{BB1}, V_{BB2} | Output Voltage Reference; NOTE 2 | | | -1.3 | | V |

NOTE 1: Outputs terminated with 50Ω to $\mbox{V}_{\mbox{CC}}$ – 2V.

NOTE 2: Single-ended input operation is limited. $V_{CC} \ge 3V$ in LVPECL mode.

AC Electrical Characteristics

Table 5. AC Characteristics, $V_{CC} = 2.375V$ to 3.465V; $V_{EE} = 0V$ or $V_{CC} = 0V$; $V_{EE} = -3.8V$ to -2.375V, $T_A = -40^{\circ}C$ to $85^{\circ}C$

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|---------------------------------|--|---|---------|---------|---------|-------|
| f _{MAX} | Output Frequency | | | | 3 | GHz |
| <i>t</i> jit | Additive Phase Jitter, RMS; refer to Additive Phase Jitter section | 622.08MHz, 12kHz – 20MHz | | 0.073 | | ps |
| t _{PD} | Propagation Delay; NOTE 1 | | 300 | | 615 | ps |
| tsk(pp) | Part-to-Part Skew; NOTE 2, 3 | | | | 250 | ps |
| t _R / t _F | Output Rise/Fall Time | 20% to 80% | 70 | | 220 | ps |
| MUX _{ISOLATION} | MUX Isolation | 622.08MHz, V _{IN} 1.6V to 2.4V | | -59 | | dB |

All parameters measured up to 1.5GHz, unless otherwise noted.

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

NOTE 1: Measured from the differential input crossing point to the differential output crossing point.

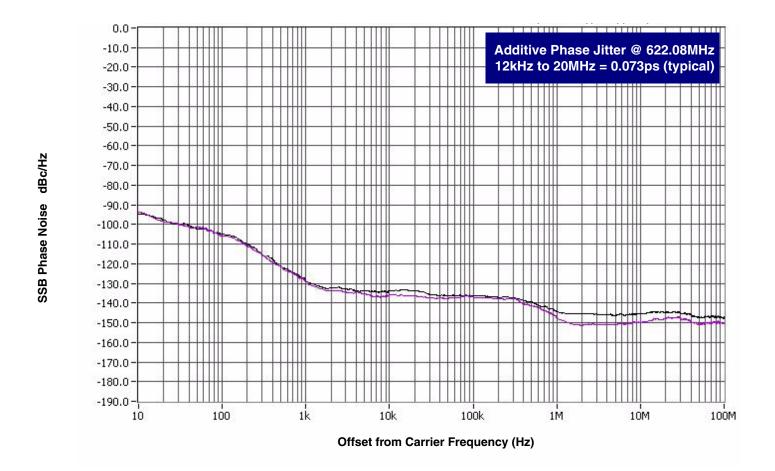
NOTE 2: Defined as skew between outputs on different devices operating at the same supply voltage and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at the differential cross points.

NOTE 3: This parameter is defined according with JEDEC Standard 65.

Additive Phase Jitter

The spectral purity in a band at a specific offset from the fundamental compared to the power of the fundamental is called the *dBc Phase Noise*. This value is normally expressed using a Phase noise plot and is most often the specified plot in many applications. Phase noise is defined as the ratio of the noise power present in a 1Hz band at a specified offset from the fundamental frequency to the power value of the fundamental. This ratio is expressed in decibels (dBm) or a ratio

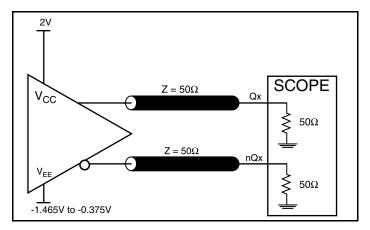
of the power in the 1Hz band to the power in the fundamental. When the required offset is specified, the phase noise is called a *dBc* value, which simply means dBm at a specified offset from the fundamental. By investigating jitter in the frequency domain, we get a better understanding of its effects on the desired application over the entire time record of the signal. It is mathematically possible to calculate an expected bit error rate given a phase noise plot.



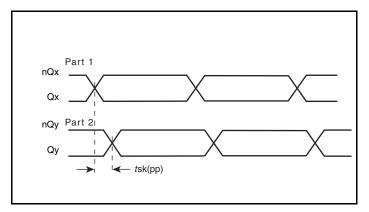
As with most timing specifications, phase noise measurements has issues relating to the limitations of the equipment. Often the noise floor of the equipment is higher than the noise floor of the device. This

is illustrated above. The device meets the noise floor of what is shown, but can actually be lower. The phase noise is dependent on the input source and measurement equipment.

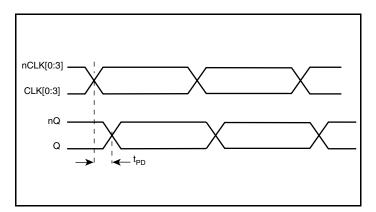
Parameter Measurement Information



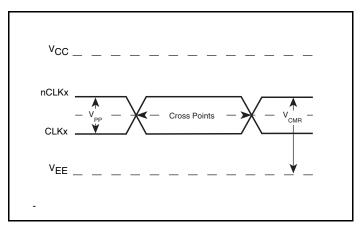
LVPECL Output Load AC Test Circuit



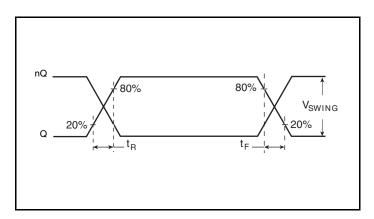
Part-to-Part Skew



Propagation Delay



Differential Input Level



Output Rise/Fall Time

Application Information

Wiring the Differential Input to Accept Single-Ended Levels

Figure 1 shows how the differential input can be wired to accept single-ended levels. The reference voltage V_REF = $V_{CC}/2$ is generated by the bias resistors R1, R2 and C1. This bias circuit should be located as close as possible to the input pin. The ratio of R1 and R2 might need to be adjusted to position the V_REF in the center of the input voltage swing. For example, if the input clock swing is only 2.5V and $V_{CC} = 3.3V$, V_REF should be 1.25V and R2/R1 = 0.609.

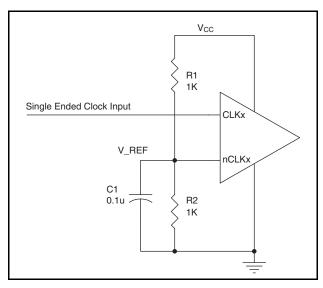


Figure 1. Single-Ended Signal Driving Differential Input

Recommendations for Unused Input Pins

Inputs:

CLK/nCLK Inputs

For applications not requiring the use of the differential input, a $1 k\Omega$ resistor should be tied from nCLK to $V_{CC}.$

Single-ended LVPECL Control Pins

All control pins have internal pulldowns; additional resistance is not required but can be added for additional protection. A $1k\Omega$ resistor can be used.

Clock Input Interface

The CLK/nCLK accepts LVPECL, LVDS, CML, SSTL and other differential signals. Both V_{SWING} and V_{OH} must meet the V_{PP} and V_{CMR} input requirements. Figures 2A to2E show interface examples for the HiPerClockS CLK /nCLK input driven by the most common

Figure 2A. HiPerClockS CLK/nCLK Input Driven by a CML Driver

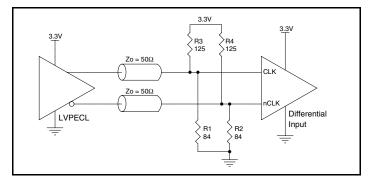


Figure 2C. HiPerClockS CLK/nCLK Input
Driven by a 3.3V LVPECL Driver

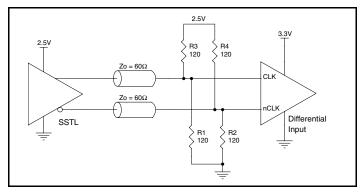


Figure 2E. HiPerClockS CLK/nCLK Input Driven by an SSTL Driver

driver types. The input interfaces suggested here are examples only. If the driver is from another vendor, use their termination recommendation. Please consult with the vendor of the driver component to confirm the driver termination requirements.

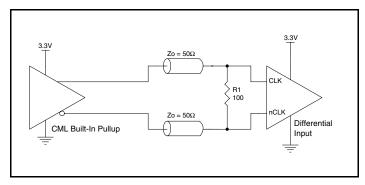


Figure 2B. HiPerClockS CLK/nCLK Input
Driven by a Built-In Pullup CML Driver

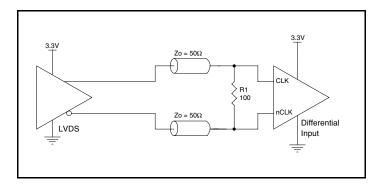


Figure 2D. HiPerClockS CLK/nCLK Input Driven by a 3.3V LVDS Driver

Termination for 3.3V LVPECL Outputs

The clock layout topology shown below is a typical termination for LVPECL outputs. The two different layouts mentioned are recommended only as guidelines.

The differential outputs are low impedance follower outputs that generate ECL/LVPECL compatible outputs. Therefore, terminating resistors (DC current path to ground) or current sources must be used for functionality. These outputs are designed to drive 50Ω

 $Z_{o} = 50\Omega$ $Z_{o} = 50\Omega$ $RTT = \begin{bmatrix} 1 \\ ((V_{OH} + V_{OL}) / (V_{CC} - 2)) - 2 \end{bmatrix} * Z_{o}$ $RTT = \begin{bmatrix} 1 \\ ((V_{OH} + V_{OL}) / (V_{CC} - 2)) - 2 \end{bmatrix} * Z_{o}$

Figure 3A. 3.3V LVPECL Output Termination

transmission lines. Matched impedance techniques should be used to maximize operating frequency and minimize signal distortion. *Figures 3A and 3B* show two different layouts which are recommended only as guidelines. Other suitable clock layouts may exist and it would be recommended that the board designers simulate to guarantee compatibility across all printed circuit and clock component process variations.

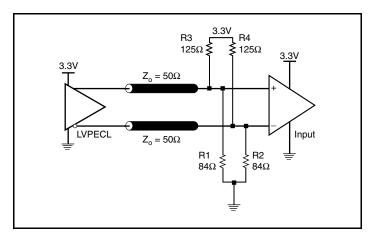


Figure 3B. 3.3V LVPECL Output Termination

Termination for 2.5V LVPECL Outputs

Figure 4A and Figure 4B show examples of termination for 2.5V LVPECL driver. These terminations are equivalent to terminating 50Ω to V_{CC} – 2V. For V_{CC} = 2.5V, the V_{CC} – 2V is very close to ground

level. The R3 in Figure 4B can be eliminated and the termination is shown in *Figure 4C*.

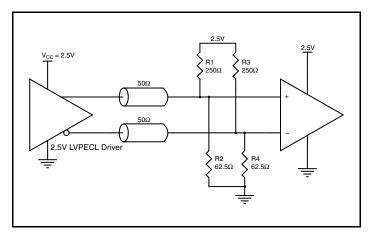


Figure 4A. 2.5V LVPECL Driver Termination Example

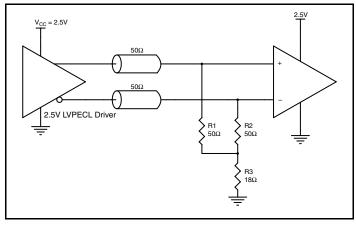


Figure 4B. 2.5V LVPECL Driver Termination Example

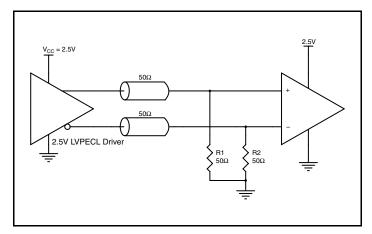


Figure 4C. 2.5V LVPECL Driver Termination Example

Power Considerations

This section provides information on power dissipation and junction temperature for the ICS53S057I. Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the ICS53S057I is the sum of the core power plus the power dissipated in the load(s).

The following is the power dissipation for $V_{CC} = 3.3V + 5\% = 3.465V$, which gives worst case results.

NOTE: Please refer to Section 3 for details on calculating power dissipated in the load.

- Power (core)_{MAX} = V_{CC MAX} * I_{EE MAX} = 3.465V * 25mA = 86.625mW
- Power (outputs)_{MAX} = 31.1mW/Loaded Output pair

Total Power_MAX (3.3V, with all outputs switching) = 86.625mW + 31.1mW = 117.725mW

2. Junction Temperature.

Junction temperature, Tj, is the temperature at the junction of the bond wire and bond pad and directly affects the reliability of the device. The maximum recommended junction temperature for HiPerClockS devices is 125°C.

The equation for Tj is as follows: Tj = θ_{JA} * Pd_total + T_A

Tj = Junction Temperature

 θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_total = Total Device Power Dissipation (example calculation is in section 1 above)

T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming no air flow and a multi-layer board, the appropriate value is 87.2°C/W per Table 6 below.

Therefore, Tj for an ambient temperature of 85°C with all outputs switching is:

 $85^{\circ}\text{C} + 0.118\text{W} * 87.2^{\circ}\text{C/W} = 95.3^{\circ}\text{C}$. This is well below the limit of 125°C .

This calculation is only an example. Tj will obviously vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (multi-layer).

Table 6. Thermal Resistance θ_{JA} for 20 Lead TSSOP, Forced Convection

| θ_{JA} by Velocity | | | | |
|---|----------|----------|----------|--|
| Meters per Second | 0 | 1 | 2.5 | |
| Multi-Layer PCB, JEDEC Standard Test Boards | 87.2°C/W | 82.9°C/W | 80.7°C/W | |

3. Calculations and Equations.

The purpose of this section is to derive the power dissipated into the load.

LVPECL output driver circuit and termination are shown in Figure 5.

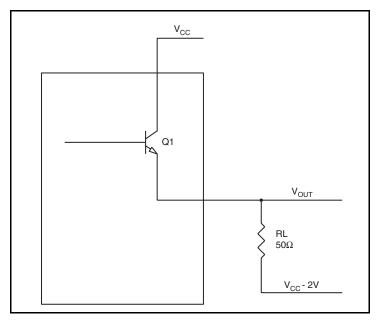


Figure 5. LVPECL Driver Circuit and Termination

To calculate worst case power dissipation into the load, use the following equations which assume a 50Ω load, and a termination voltage of V_{CC} = 2V.

- For logic high, $V_{OUT} = V_{OH_MAX} = V_{CC_MAX} 0.935V$ $(V_{CC_MAX} V_{OH_MAX}) = 0.935V$
- For logic low, $V_{OUT} = V_{OL_MAX} = V_{CC_MAX} 1.67V$ $(V_{CC_MAX} V_{OL_MAX}) = 1.67V$

Pd_H is power dissipation when the output drives high.

Pd_L is the power dissipation when the output drives low.

$$Pd_H = [(V_{OH_MAX} - (V_{CC_MAX} - 2V))/R_L] * (V_{CC_MAX} - V_{OH_MAX}) = [(2V - (V_{CC_MAX} - V_{OH_MAX}))/R_L] * (V_{CC_MAX} - V_{OH_MAX}) = [(2V - 0.935V)/50\Omega] * 0.935V = \textbf{19.9mW}$$

$$Pd_{L} = [(V_{OL_MAX} - (V_{CC_MAX} - 2V))/R_{L}] * (V_{CC_MAX} - V_{OL_MAX}) = [(2V - (V_{CC_MAX} - V_{OL_MAX}))/R_{L}] * (V_{CC_MAX} - V_{OL_MAX}) = [(2V - 1.67V)/50\Omega] * 1.67V = 11.2mW$$

Total Power Dissipation per output pair = Pd_H + Pd_L = 31.1mW

Reliability Information

Table 7. θ_{JA} vs. Air Flow Table for a 20 Lead TSSOP

| θ_{JA} by Velocity | | | | |
|---|----------|----------|----------|--|
| Meters per Second | 0 | 1 | 2.5 | |
| Multi-Layer PCB, JEDEC Standard Test Boards | 87.2°C/W | 82.9°C/W | 80.7°C/W | |

Transistor Count

The transistor count for ICS853S057I is: 251

Package Outline and Package Dimensions

Package Outline - G Suffix for 20 Lead TSSOP

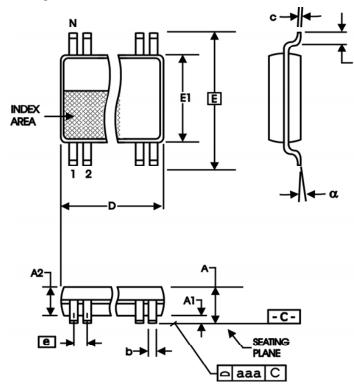


Table 8. Package Dimensions

| All Dimensions in Millimeters | | | | | |
|-------------------------------|---------------------|------|--|--|--|
| Symbol | bol Minimum Maximum | | | | |
| N | 20 | | | | |
| Α | | 1.20 | | | |
| A1 | 0.05 | 0.15 | | | |
| A2 | 0.80 1.05 | | | | |
| b | 0.19 | 0.30 | | | |
| С | 0.09 | 0.20 | | | |
| D | 6.40 | 6.60 | | | |
| E | 6.40 Basic | | | | |
| E1 | 4.30 | 4.50 | | | |
| е | 0.65 Basic | | | | |
| L | 0.45 | 0.75 | | | |
| α | 0° | 8° | | | |
| aaa | | 0.10 | | | |

Reference Document: JEDEC Publication 95, MO-153

Ordering Information

Table 9. Ordering Information

| Part/Order Number | Marking | Package | Shipping Packaging | Temperature |
|-------------------|--------------|---------------------------|--------------------|---------------|
| 853S057AGILF | ICS53S057AIL | "Lead-Free" 20 Lead TSSOP | Tube | -40°C to 85°C |
| 853S057AGILFT | ICS53S057AIL | "Lead-Free" 20 Lead TSSOP | 2500 Tape & Reel | -40°C to 85°C |

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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Revision History Sheet

| Rev | Table | Page | Description of Change | Date |
|-----|-------|--------|--|-----------|
| А | T5 | 4 7 | AC Characteristics Table - added Thermal Note. Recommendations for Unused Input Pins - modified CLK/nCLK Input paragraph. Changed datasheet Header/Footer. | 7/30/09 |
| Α | T1 | 2 | Pin Description Table - Pins 18 and 19 (SELx description) added LVCMOS levels. | 5/16/2012 |

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